Special Topics in Structures: Residual Stress and Energy Methods

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* With thanks to Steve Senturia, from whose lecture notes some of these materials are adapted.

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Outline

- > Effects of residual stresses on structures
- > Energy methods
 - Elastic energy
 - Principle of virtual work: variational methods
 - Examples
- > Rayleigh-Ritz methods for resonant frequencies and extracting lumped-element masses for structures

Reminder: Thin Film Stress

- If a thin film is adhered to a substrate, mismatch of thermal expansion coefficient between film and substrate can lead to stresses in the film (and, to a lesser degree, stresses in the substrate)
- > Residual stress can also come from film structure: intrinsic stress
- > Stresses set up bending moments that can bend the substrate
- > When we release a residually stressed MEMS structure, interesting effects can ensue

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Reminder: Differential equation of beam bending

> Small angle bending:



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> Beam equation:

- q = distributed load
- w = vertical displacement
- x = axial position along beam

 ${\mathcal W}$

Example: Fixed-fixed beam

- > Fixed-fixed beams are common in MEMS: switches, diffraction gratings, flexures
- > Example: Silicon Light Machines Grating Light Valve display deflects a beam in order to diffract light

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Please see: Figure 1.4 in Senturia, Stephen D. Microsystem Design. Boston, MA: Kluwer Academic Publishers, 2001, p. 7. ISBN: 9780792372462.

> Residual stress in beams can enhance or reduce response to an applied load, and impact flatness of actuated beam

> Residual stress can be included in the basic beam bending equation by the addition of an extra term

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Residual Axial Stress in Beams

- > Residual axial stress in a beam contributes to its bending stiffness
- > Leads to the Euler beam equation



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$$2\rho WP_0 = 2\sigma_0 WH$$

$$\Rightarrow P_0 = \frac{\sigma_0 H}{\rho}$$

which is equivalent to a distributed load

$$q_0 = P_0 W = \sigma_0 W H \frac{d^2 w}{dx^2}$$

Insert as added load into beam equation :



Example: Effect of tensile stress on stiffness



Image by MIT OpenCourseWare.

Adapted from Figure 9.17 in Senturia, Stephen D. *Microsystem Design.* Boston, MA: Kluwer Academic Publishers, 2001, p. 232. ISBN: 9780792372462.

100 μm long, 2 μm wide, 2 μm high fixed-fixed silicon beam

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Stress impacts flatness: leveraged bending

> Pull-in is modified if the actuating electrodes are away from the point of closest approach



Figure 3 on p. 499 in: Hung, E. S., and S. D. Senturia. "Extending the Travel Range of Analog-tuned Electrostatic Actuators." *Journal of Microelectromechanical Systems* 8, no. 4 (December 1999): 497-505. © 1999 IEEE.

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Buckling of Axially Loaded Beams

- If the compressive stress is too large, a beam will spontaneously bend – this is called *buckling*
- > The basic theory of buckling is in Sec. 9.6.3
- > The Euler buckling criterion:

$$\sigma_{Euler} = -\frac{\pi^2}{3} \frac{EH^2}{L^2}$$

Plates with in-plane stress and membranes

> As with the Euler beam equation, in plane stress can be included

$$D\left(\frac{\partial^4 w}{\partial x^4} + 2\frac{\partial^4 w}{\partial x^2 \partial y^2} + \frac{\partial^4 w}{\partial y^4}\right) - \left(\frac{N_x}{W}\frac{\partial^2 w}{\partial x^2} + \frac{N_y}{W}\frac{\partial^2 w}{\partial y^2}\right) = P(x, y)$$

Axial stresses in x

> When tensile stress dominates over flexural rigidity (thin, tensioned plate), the plate may be considered a membrane

and y directions

$$\left(\frac{N_x}{W}\frac{\partial^2 w}{\partial x^2} + \frac{N_y}{W}\frac{\partial^2 w}{\partial y^2}\right) = -P$$

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How about cantilevers?

- > Example: residually stressed cantilever, where stress is constant throughout structure
- > Before release: stressed cantilever is attached to surface
- > After release: cantilever relieves stress by expanding or contracting to its desired length
- > No bending of released structure

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How about nonuniform axial stress?

- > Nonuniform axial stress through the thickness of a beam creates a bending moment
- > It can arise from two sources
 - Intrinsic stress gradients, created during formation of the cantilever material (e.g. polysilicon)
 - Residual stress in thin films deposited onto the cantilever
- > The bending moment curls the cantilever

Example: Cantilever with stress gradient

Think about it in three steps:

- Relax the average stress to zero after release
- Compute the moment when the beam is flat
- Compute the curvature that results from the moment



Image by MIT OpenCourseWare.

Adapted from Figure 9.13 in Senturia, Stephen D. *Microsystem Design*. Boston, MA: Kluwer Academic Publishers, 2001, p. 223. ISBN: 9780792372462.

$$M_x = \int_A z \sigma_x dA = -\frac{1}{6} W H^2 \sigma_1$$
 and $\rho_x = -\frac{EI}{M_x} \Longrightarrow \rho_x = \frac{1}{2} \frac{EH}{\sigma_1}$

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Example: Thin Film on Cantilever

> In this case, the curling does not relieve all the stress



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> See text for math



Barbastathis group, MIT

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Outline

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 - Examples
- > Rayleigh-Ritz methods for resonant frequencies and extracting lumped-element masses for structures

Elastic Energy

> Elastic stored energy density is the integral of stress with respect to strain

> Elastic energy density : $\widetilde{W}(x,y,z) = \int_0^{\varepsilon(x,y,z)} \sigma(\varepsilon) d\varepsilon$ When $\sigma(\varepsilon) = E\varepsilon$: $\widetilde{W}(x,y,z) = \frac{1}{2} E[\varepsilon(x,y,z)]^2$

> The total elastic stored energy is the volume integral of the elastic energy density

Total stored elastic energy: $W = \iiint \widetilde{W}(x,y,z) dx dy dz$

Volume

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Including Shear Strains

- > More generally, the energy density in a linear elastic medium is related to the product of stress and strain
- > A similar approach can be used for electrostatic stored energy density (1/2)D*E and magnetostatic stored energy density (1/2)B*H.

For axial strains :
$$\widetilde{W} = \frac{1}{2}\sigma\varepsilon$$

For shear strains : $\widetilde{W} = \frac{1}{2}\tau\gamma$
This leads to a total elastic strain energy :
 $W = \frac{1}{2} \iiint (\sigma_x \varepsilon_x + \sigma_y \varepsilon_y + \sigma_z \varepsilon_z + \tau_{xy} \gamma_{xy} + \tau_{xz} \gamma_{xz} + \tau_{yz} \gamma_{yz}) dxdydz$

Concept: Principle of Virtual Work

> The question: how to determine the deformation that results from an applied load



- > Known: the work done on an energy-conserving system by external forces must result in an equal amount of stored potential energy
- > Imposing this condition can provide an exact solution to many problems
 - For example, if functional dependence between quantities is known, and you just need to find what the actual values are

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Concept: Principle of Virtual Work

> Can approach this from a "guessing" point of view

 Guess values for δ; whichever one best equates stored energy and work done is the right answer



- > What if you don't know the functional form of your deformations/displacements – does this still work?
- > Yes! You can choose a plausible shape function for the displacement with a few adjustable parameters and iteratively "guess" the constants to best equate stored energy and work done

Principle of Virtual Work

- > Goal: a variational method for solving energy-conserving problems (a mathematical way of approaching the "guessing")
- > Define total potential U, including work and stored energy

U = Stored energy - Work done

- > A system in equilibrium has a total potential U that is a minimum with respect to any virtual displacement
 - No matter what you change, you won't get any closer to matching work and stored energy
- > Requirement: the virtual displacement must obey B.C.
- > Nomenclature for small virtual displacements
 - In the x direction: δu
 - In the y direction: δv
 - In the z direction: δw

Math: Principle of Virtual Work

> Consider all possible virtual displacements; evaluate change in strains

$$\delta \varepsilon_x = \frac{\partial}{\partial x} \delta u$$
 and $\delta \gamma_{xy} = \left(\frac{\partial}{\partial x} \delta v + \frac{\partial}{\partial y} \delta u\right)$

> This implies changes in strain energy density

$$\delta \widetilde{W} = \sigma_x \delta \varepsilon_x + \ldots + \tau_{xy} \delta \gamma_{xy} + \ldots$$

> The principle of virtual work states that in equilibrium, for any virtual displacement that is compatible with the B.C.,

$$\begin{split} \iiint \delta \widetilde{W} dx dy dz &- \iint \left(F_{s,x} \delta u + F_{s,y} \delta v + F_{s,z} \delta w \right) dS \\ &- \iiint \left(F_{b,x} \delta u + F_{b,y} \delta v + F_{b,z} \delta w \right) dx dy dz = 0 \end{split}$$

Differential Version

> The previous equation is equivalent to the following:

$$\delta \left[\iiint_{Volume} \widetilde{W} dx dy dz - \iint_{Surface} (F_{s,x}u + F_{s,y}v + F_{s,z}w) dS - \iiint_{Volume} (F_{b,x}u + F_{b,y}v + F_{b,z}w) dx dy dz \right] = 0$$

This can be restated in the following form :

 $\delta U = 0$

where

_

$$U = \left[\iiint_{Volume} \widetilde{W} dx dy dz - \iint_{Surface} (F_{s,x}u + F_{s,y}v + F_{s,z}w) dS - \iiint_{Volume} (F_{b,x}u + F_{b,y}v + F_{b,z}w) dx dy dz \right]$$

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- > Select a trial solution with parameters that can be varied
 - $\hat{u}(x, y, z; c_1, c_2, ..., c_n) = trial displacement in x$
 - v(x, y, z; c₁, c₂,...c_n) = trial displacement in y
 - $\hat{\hat{w}}(x, y, z; c_1, c_2, ..., c_n)$ = trial displacement in z
- Formulate the total potential U of the system as functions of these parameters
- > Find the potential minimum with respect to the values of the parameters

$$\frac{\partial U}{\partial c_1} = 0, \quad \frac{\partial U}{\partial c_2} = 0, \dots, \quad \frac{\partial U}{\partial c_n} = 0$$

> The result is the best solution possible with the assumed trial function

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Why Bother?

- > Nonlinear partial differential equations are basically very nasty.
- > Approximate analytical solutions can always be found with variational methods
- > The analytical solutions have the correct dependence on geometry and material properties, hence, serve as the basis for good macro-models
- > Accurate numerical answers may require finite-element modeling

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Analytic vs. Numerical

- > Analytic variational methods and numerical finite-element methods both depend on the Principal of Virtual Work
- > Both methods minimize total potential energy
- > FEM methods use local trial functions (one per element). Variational parameters are the nodal displacements
- > Analytic methods use global trial functions

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Example: fixed-fixed beam, small deflections

- > Doubly-fixed beam with a point load at some position along the beam, in the small deflection limit
- > Our present choice: use a fourth degree polynomial trial solution

$$\hat{w}(x) = c_0 + c_1 x + c_2 x^2 + c_3 x^3 + c_4 x^4$$

Boundary conditions: w = 0 and w' = 0 at x = 0, L

- > Apply boundary conditions:
 - c₀ = c₁ = 0 from BC at x = 0
 - BC at x = L eliminate two more constants
 - Result is a shape function with one undetermined amplitude parameter

$$\hat{w}(x) = c_4 \left(L^2 x^2 - 2L x^3 + x^4 \right)$$

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Example: fixed-fixed beam, small deflections

- > Formulate total potential energy and find the minimum
- > Calculate strain energy from bending

width of beam
$$\mathcal{E} = -\frac{z}{\rho} = -z\frac{d^2\hat{w}}{dx^2} = -zc_4\left(2L^2 - 12Lx + 12x^2\right)$$

total strain energy $W = \frac{EW}{2}\int_0^L \int_{-H/2}^{H/2} \mathcal{E}^2 dx dz = \frac{1}{30}EWH^3L^5c_4^2$
> Calculate work done by external force applied at \mathbf{x}_0

$$Work = F\hat{w}(x_0) = Fc_4 \left(L^2 x_0^2 - 2Lx_0^3 + x_0^4\right)$$

> This yields total potential energy

$$U = \frac{1}{30} EWH^3 L^5 c_4^2 - \left(L^2 x_0^2 - 2Lx_0^3 + x_0^4\right)Fc_4$$

Example: fixed-fixed beam, small deflections

Minimize total potential energy with respect to c₄, determine c₄, and plug in to find variational solution for deflection w(x)

$$\frac{\partial U}{\partial c_4} = 0$$

$$c_4 = 15 \frac{L^2 x_0^2 - 2L x_0^3 + x_0^4}{EWH^3 L^5} F$$

$$w = 15 \frac{\left(L^2 x_0^2 - 2L x_0^3 + x_0^4\right) \left(L^2 x^2 - 2L x^3 + x^4\right)}{EWH^3 L^5} F$$
> Compare stiffness for the case of a center-applied load

$$w\left(\frac{L}{2}\right) = \frac{15}{256} \frac{L^3}{EWH^3} F$$
$$k = \frac{256}{15} \frac{EWH^3}{L^3} \approx 17 \frac{EWH^3}{L^3}$$

Recall solution of beam equation

$$k = 16 \frac{EWH^3}{L^3}$$

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Properties of the Variational Solution

- > Does it solve the beam equation? NO
- Is the point of maximum deflection near where the load is applied? NOT IN GENERAL
- > How can we determine how accurate the solution is? TRY A BETTER FUNCTION
- > Was this a good trial function? **NO**

A Better Trial Function

> Fifth-order polynomial allows both the amplitude and shape of the deformation to be varied



Image by MIT OpenCourseWare.

Adapted from Figure 10.1 in Senturia, Stephen D. *Microsystem Design*. Boston, MA: Kluwer Academic Publishers, 2001, p. 248. ISBN: 9780792372462. The artist's representation of the fourth and fifth degree polynomials is approximate.

Fourth degree polynomial

Fifth degree polynomial

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What about large deflections?

- > For small deflections, pure bending is a good approximation
 - The geometrically constructed neutral axis really does have about zero strain
- > For large deflections, the beam gets longer
 - Tensile side gets even more tensile
 - Compressed side gets less compressed
 - Neutral axis becomes tensile
- > We can treat this as a superposition of two events
 - First, the beam bends in pure bending, which draws the end of the beam away from the second support
 - Then, the beam is stretched to reconnect with the second support
 - Quantify the stretching by the strain at the originally neutral axis

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Analysis of "Large" Deflections

> When deflections are "large," on the order of the beam thickness, stretching becomes important



As a result of stretching, the arc length increases

$$ds = \sqrt{[dx + u(x + dx) - u(x)]^{2} + [w(x + dx) - w(x)]^{2}}$$
Using the result that $\sqrt{1 + \delta} = 1 + \frac{\delta}{2}$

$$ds = dx \left[1 + \frac{du}{dx} + \frac{1}{2} \left(\frac{dw}{dx} \right)^{2} \right]$$
The axial strain is given by
$$\varepsilon_{x} = \frac{ds - dx}{dx} = \frac{du}{dx} + \frac{1}{2} \left(\frac{dw}{dx} \right)^{2}$$
The change in length is
$$\delta L = \int_{-L/2}^{L/2} \frac{ds - dx}{dx} dx = \int_{-L/2}^{L/2} \varepsilon_{x} dx$$

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Example: Center-Loaded Beam

- > Potential energy has three terms:
 - Bending strain energy
 - Stretching strain energy
 - External work



Image by MIT OpenCourseWare.

Adapted from Figure 10.2 in Senturia, Stephen D. *Microsystem Design*. Boston, MA: Kluwer Academic Publishers, 2001, p. 250. ISBN: 9780792372462.

- > Bending and external work already calculated for one trial function
- > Pick another trial function (same weakness as last attempt, but easy to use) and include large deflections

$$\hat{w} = \frac{c}{2} \left(1 + \cos \frac{2\pi x}{L} \right)$$

Why not a û?

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Example: Center-Loaded Beam

> First, calculate the strain due to stretching (aggregate axial strain)

$$\varepsilon_{a} = \frac{\delta L}{L} = \frac{1}{L} \int_{-L/2}^{L/2} \varepsilon_{x} dx$$

$$\varepsilon_{a} = \frac{1}{L} \int_{-L/2}^{L/2} \left[\frac{d\hat{u}}{dx} + \frac{1}{2} \left(\frac{d\hat{w}}{dx} \right)^{2} \right] dx$$

$$\varepsilon_{a} = \frac{1}{L} \left[\hat{u} \left(\frac{L}{2} \right) - \hat{u} \left(-\frac{L}{2} \right) \right] + \frac{1}{L} \int_{-L/2}^{L/2} \left[\frac{1}{2} \left(\frac{d\hat{w}}{dx} \right)^{2} \right] dx$$

> Total strain = bending strain + aggregate axial strain

$$\varepsilon_{T} = \varepsilon_{bending} + \varepsilon_{stretching}$$
$$\varepsilon_{T} = -z \frac{d^{2} \hat{w}}{dx^{2}} + \varepsilon_{a}$$

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Example: Center-Loaded Beam

> Calculate total stored elastic energy from total strain

$$W = \frac{EW}{2} \int_{-H/2}^{H/2} \int_{-L/2}^{L/2} \varepsilon_T^2 dx dz = \frac{EWH\pi^4 (8H^2 + 3c^2)c^2}{96L^3}$$

> Finally, potential energy...

$$U = W - Fc = \frac{EWH\pi^4 (8H^2 + 3c^2)c^2}{96L^3} - Fc$$

> ...which we minimize with respect to c

$$\frac{\partial U}{\partial c} = 0 \qquad \qquad F = \left(\frac{\pi^4}{6}\right) \left[\frac{EWH^3}{L^3}\right] c + \left(\frac{\pi^4}{8}\right) \left[\frac{EWH}{L^3}\right] c^3$$
> Compare linear term with solution to beam equation: prefactor
16.2 instead of 16

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Results from example

> Force-displacement relationship: an amplitude-stiffened Duffing spring

$$F = \left(\frac{\pi^4}{6}\right) \left[\frac{EWH^3}{L^3}\right] c + \left(\frac{\pi^4}{8}\right) \left[\frac{EWH}{L^3}\right] c^3$$

Solution shows geometry dependence; constants may or may not be correct

$$F = C_b \left[\frac{EWH^3}{L^3} \right] c + C_s \left[\frac{EWH}{L^3} \right] c^3$$

> Once you've found the elastic strain energy, finding results for another load is easy

Work = Fc
$$\longrightarrow$$
 Work = $\int_{-L/2}^{L/2} q(x)\hat{w}(x)dx$

Example: uniform pressure load P

- > Adopt the elastic strain energy
- > Calculate the work for a uniform pressure load

$$Work = WP \int_{-L/2}^{L/2} \frac{c}{2} \left(1 + \cos\frac{2\pi x}{L}\right) dx = \frac{WLPc}{2}$$

> Minimize U to find relationship between load and deflection

$$P = \left(\frac{\pi^4}{3}\right) \left[\frac{EH^3}{L^4}\right] c + \left(\frac{\pi^4}{4}\right) \left[\frac{EH}{L^4}\right] c^3$$

> The geometry dependence appears!

Combining Variational and FEM Methods

- > Use the analytic variational method to find a good functional form for the result
- > Establish non-dimensional numerical parameters within the solution
- > Perform well-meshed FEM simulations over the design space
- > Fit the analytic solution to the FEM results

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Residual Stress In Clamped Structures

> Must add a new term to the elastic energy to capture the effects of the residual stress

$$\widetilde{\mathsf{W}} = \int_{-\infty}^{\varepsilon_{a}} \sigma d\varepsilon \quad \Rightarrow \quad \widetilde{\mathsf{W}} = \int_{-\infty}^{\varepsilon_{a}} (\sigma_{0} + E\varepsilon) d\varepsilon$$

> Now there is a residual stress term in the stored elastic energy

$$W_r = \sigma_0 W \int_{W/2}^{H/2} dz \int_{W/2}^{-L/2} \varepsilon_a dx$$

> For the fixed-fixed beam example, the residual stress term is:

$$W_r = \sigma_0 WLH \left(\frac{\pi^2}{4L^2}\right) c^2$$

> This leads to a general form of the load-deflection relationship for beams, which can be extended to plates and membranes

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Results for Doubly-Clamped Beam

For the case of a central point load :

$$F = \left\{ \left(\frac{\pi^2}{2}\right) \left[\frac{\sigma_0 WH}{L}\right] + \left(\frac{\pi^4}{6}\right) \left[\frac{EWH^3}{L^3}\right] \right\} c + \left(\frac{\pi^4}{8}\right) \left[\frac{EWH}{L^3}\right] c^3$$
and for the pressure loaded case :

$$P = \left\{ \pi^2 \left[\frac{\sigma_0 H}{L^2}\right] + \left(\frac{\pi^4}{3}\right) \left[\frac{EH^3}{L^4}\right] \right\} c + \left(\frac{\pi^4}{4}\right) \left[\frac{EH}{L^4}\right] c^3$$

The general form for pressure loading, useful for fitting to FEM results, is :

$$P = \left\{ C_r \left[\frac{\sigma_0 H}{L^2} \right] + C_b \left[\frac{EH^3}{L^4} \right] \right\} c + C_s \left[\frac{EH}{L^4} \right] c^3$$

Finally, we note that the stress term dominates over bending when

$$\sigma_0 \ge \frac{EH^2}{L^2}$$

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Outline

- > Effects of residual stresses on structures
- > Energy methods
 - Elastic energy
 - Principle of virtual work: variational methods
 - Examples
- > Rayleigh-Ritz methods for resonant frequencies and extracting lumped-element masses for structures

Estimating Resonance Frequencies

- > We have achieved part of our goal of converting structures into lumped elements
 - We can calculate elastic stiffness of almost any structure, for small and large deflections
 - But we still don't know how to find the mass term associated with structures
- > We can get the mass term from the resonance frequency and the stiffness
- > The resonance frequency comes from Rayleigh-Ritz analysis
 - In simple harmonic motion at resonance, the maximum kinetic energy equals the maximum potential energy
 - Determine kinetic energy; equate its maximum value to the maximum potential energy; find ω_0 .

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Estimating Resonance Frequencies

> Guess a time dependent trial function from $\hat{w}(x)$

 $\hat{w}(x,t) = \hat{w}(x)\cos(\omega t)$

> Find maximum kinetic energy from maximum velocity

Maximum velocity: $\left(\frac{\partial \hat{w}(x,t)}{\partial t}\right)_{t=\pi/2\omega} = -\omega \hat{w}(x)$ Max kinetic energy, lumped: $W_{k,\max} = \frac{1}{2}mv_{\max}^2$ Max kinetic energy density: $\widetilde{W}_{k,\max} = \frac{1}{2}\rho_m(x)\omega^2 \hat{w}(x)^2$ Max kinetic energy: $W_{k,\max} = \frac{\omega^2}{2} \iiint_{volume beam} \rho_m(x)\hat{w}(x)^2 dx dy dz$

> Calculate maximum potential energy from ŵ(x) as before

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- > The resonance frequency is obtained from the ratio of potential energy to kinetic energy, using a variational trial function
- > The result is remarkably insensitive to the specific trial function

$$\omega_0^2 = \frac{\mathsf{W}_{elastic}}{\frac{1}{2} \iint\limits_{Volume}} \rho_m(x) \hat{w}^2(x) dx$$

Example: Tensioned Beam

- > Compare two trial solutions:
 - Tensioned wire the exact solution (1/2 λ of a cosine)
 - Bent beam a very poor solution



Image by MIT OpenCourseWare. Adapted from Figure 10.3 in Senturia, Stephen D. *Microsystem Design*. Boston, MA: Kluwer Academic Publishers, 2001, p. 263. ISBN: 9780792372462.

> Resonant frequencies differ by only 15%

> Worse trial functions yield higher stiffness, higher resonant frequencies

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Extracting Lumped Masses

- > Use variational methods to calculate the stiffness
- > Use Rayleigh-Ritz with the same trial function to calculate the resonant frequency ω^2
- > Extract the mass from the relation between mass, stiffness, and resonant frequency.
 - ω² = k/m

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